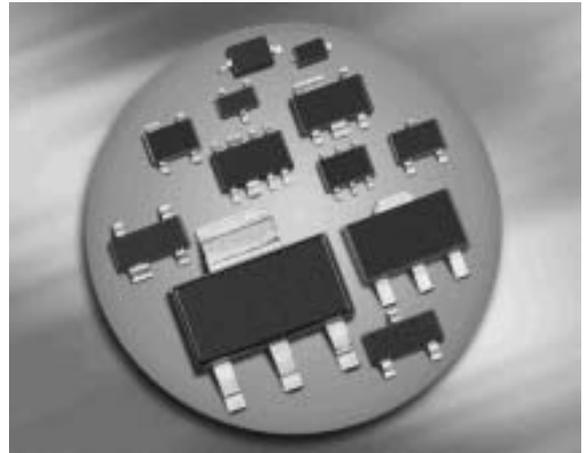
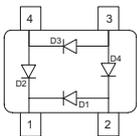


Silicon Switching Diode Array

- Bridge configuration
- High-speed switching diode chip
- Pb-free (RoHS compliant) package ¹⁾
- Qualified according AEC Q101


BGX50A


| Type | Package | Configuration | Marking |
|--------|---------|---------------|---------|
| BGX50A | SOT143 | bridge | U1s |

Maximum Ratings at $T_A = 25^\circ\text{C}$, unless otherwise specified

| Parameter | Symbol | Value | Unit |
|--|-----------|-------------|------|
| Diode reverse voltage | V_R | 50 | V |
| Peak reverse voltage | V_{RM} | 70 | |
| Forward current | I_F | 140 | mA |
| Non-repetitive peak surge forward current | I_{FSM} | - | |
| Total power dissipation $T_S \leq 74^\circ\text{C}$ | P_{tot} | 210 | mW |
| Junction temperature | T_j | 150 | °C |
| Storage temperature | T_{stg} | -65 ... 150 | |

Thermal Resistance

| Parameter | Symbol | Value | Unit |
|--|------------|-------|------|
| Junction - soldering point ²⁾ BGX50A | R_{thJS} | 360 | K/W |

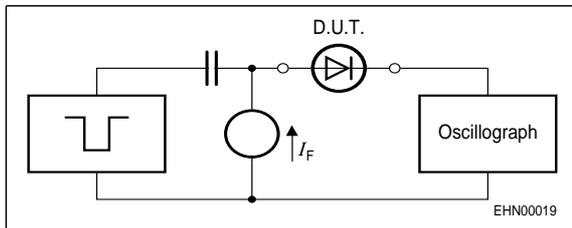
¹Pb-containing package may be available upon special request

²For calculation of R_{thJA} please refer to Application Note Thermal Resistance

Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

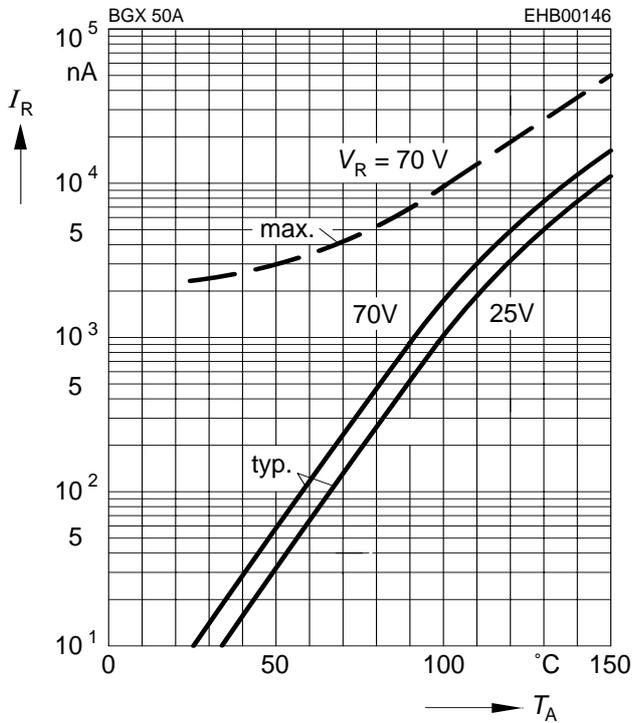
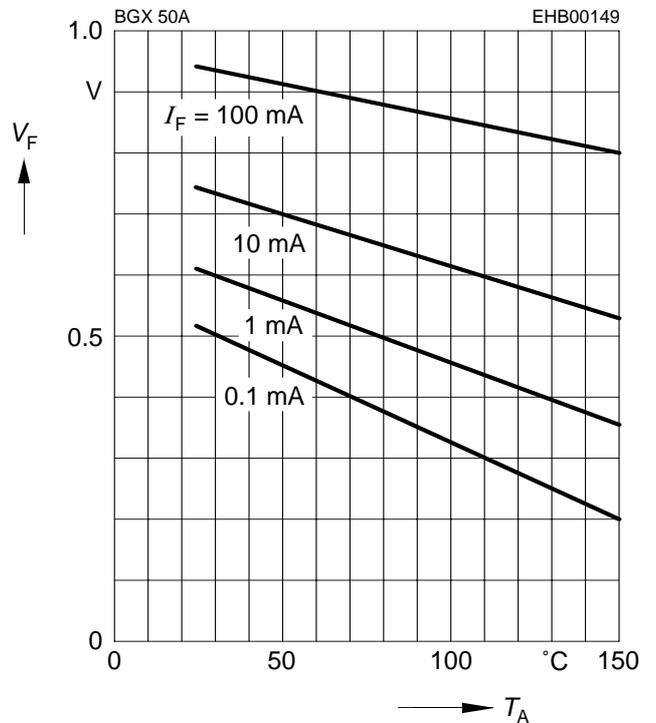
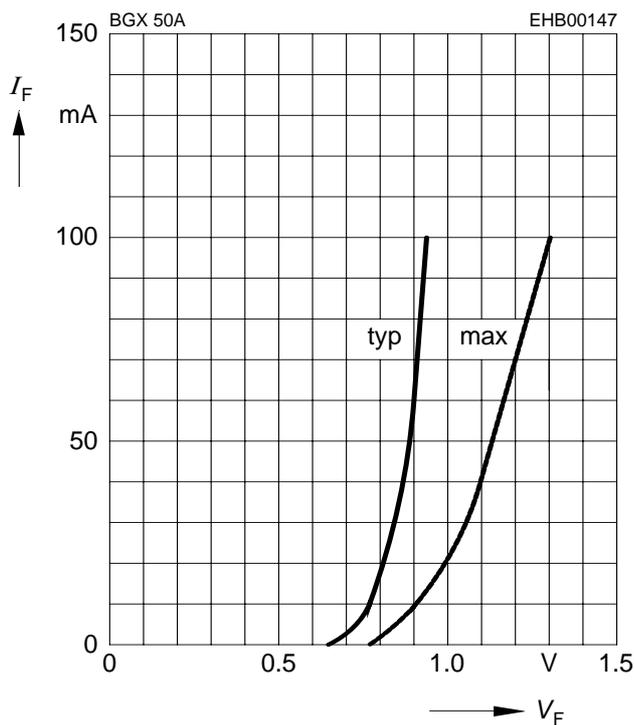
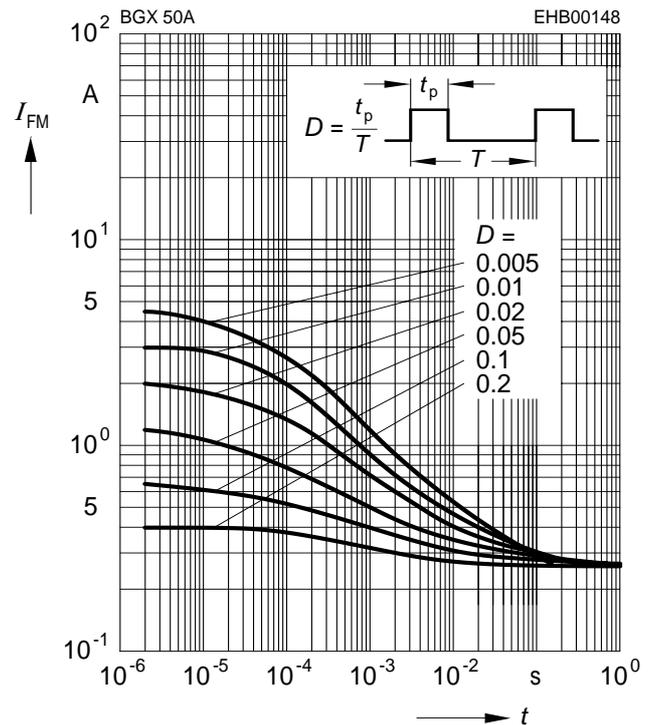
| Parameter | Symbol | Values | | | Unit |
|--|------------|--------|------|------|---------------|
| | | min. | typ. | max. | |
| DC Characteristics | | | | | |
| Breakdown voltage | $V_{(BR)}$ | - | - | - | |
| Reverse current | I_R | | | | μA |
| $V_R = 50\text{ V}$ | | - | - | 0.2 | |
| $V_R = 50\text{ V}, T_A = 150^\circ\text{C}$ | | - | - | 100 | |
| Forward voltage | V_F | - | - | 1.3 | V |
| $I_F = 100\text{ mA}$ | | | | | |

| | | | | | |
|---|----------|---|---|-----|---------------|
| AC Characteristics | | | | | |
| Diode capacitance | C_T | - | - | 1.5 | μF |
| $V_R = 0\text{ V}, f = 1\text{ MHz}$ | | | | | |
| Reverse recovery time | t_{rr} | - | - | 6 | ns |
| $I_F = 10\text{ mA}, I_R = 10\text{ mA}$, measured at $I_R = 1\text{ mA}$, $R_L = 100\ \Omega$ | | | | | |

Test circuit for reverse recovery time


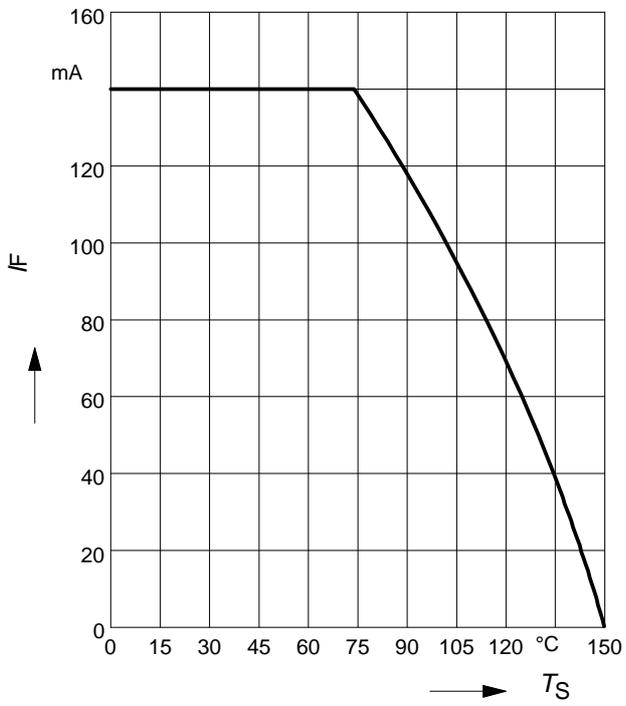
Pulse generator: $t_p = 100\text{ ns}$, $D = 0.05$, $t_r = 0.6\text{ ns}$,
 $R_i = 50\ \Omega$

Oscilloscope: $R = 50\ \Omega$, $t_r = 0.35\text{ ns}$, $C \leq 1\text{ pF}$

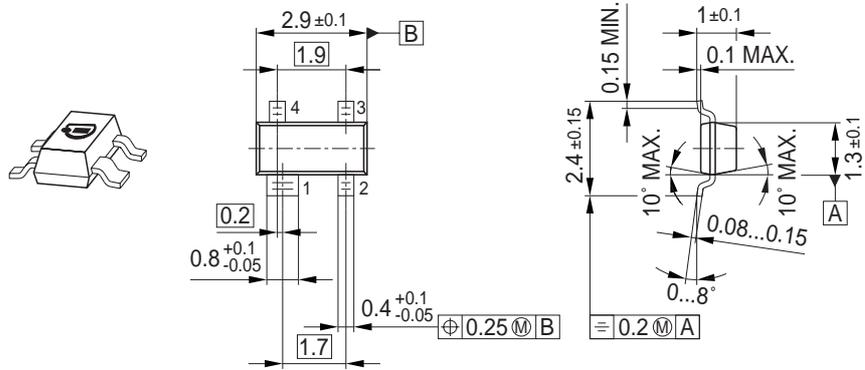
Reverse current $I_R = f(T_A)$
 $V_R = \text{Parameter}$

Forward Voltage $V_F = f(T_A)$
 $I_F = \text{Parameter}$

Forward current $I_F = f(V_F)$
 $T_A = 25^\circ\text{C}$

Peak forward current $I_{FM} = f(t_p)$
 $T_A = 25^\circ\text{C}$


Forward current $I_F = f(T_S)$

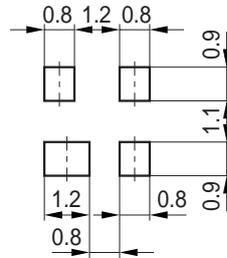
BGX50A



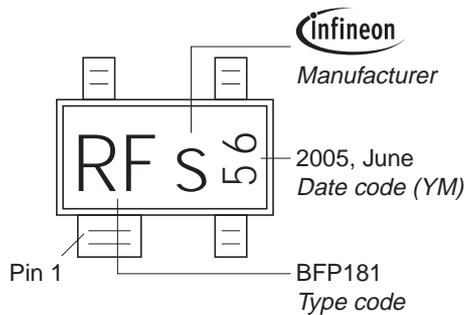
Package Outline



Foot Print



Marking Layout (Example)



Standard Packing

Reel $\varnothing 180$ mm = 3.000 Pieces/Reel
 Reel $\varnothing 330$ mm = 10.000 Pieces/Reel

